查询SN54F240供应商

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Package Options Include Plastic Small-Outline (SOIC) and Shrink Small-Outline (SSOP) Packages, Ceramic Chip Carriers, and Plastic and Ceramic DIPs

description

These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the 'F241 and 'F244, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical OE (active-low output-enable) inputs, and complementary OE and OE inputs.

The 'F240 is organized as two 4-bit buffers/line drivers with separate output enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

The SN74F240 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54F240 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74F240 is characterized for operation from 0°C to 70°C.

OCTAL BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS
SDFS061A - D2932, MARCH 1987 - REVISED OCTOBER 1993

走多邦,专业PCB打样工厂,2-5N546246, SN74F240

SN74F240 DB, DW, OR N PACKAGE (TOP VIEW)								
1 <u>0</u> [20	V _{cc}					
1A1 [2	19	2OE					
2Y4 [3	18	1Y1					
1A2 [4	17	2A4					
2Y3 [5	16	1Y2					
1A3 [6	15	2A3					
2Y2 [7	14	1Y3					
1A4 [8	13	2A2					
2Y1 [9	12	1Y4					
GND [10	11	2A1					

SN54F240 ... J PACKAGE

SN54F240 ... FK PACKAGE (TOP VIEW)

2 <u>4</u> 1 <u>10</u> 2 <u>0</u> 2 <u>0</u> 20 <u>6</u>	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	
1A2 4 18 1Y1 2Y3 5 17 2A4 1A3 6 16 1Y2 2Y2 7 15 2A3 1A4 8 14 1Y3 9 10 11 12	

FUNCTION TABLE (each buffer)								
INPUTS OUTPUT								
OE	Α	Y						
L	Н	L						
L	L	н						
н	Х	z						
- C. 14								

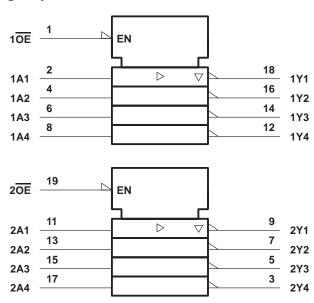
电子市场向 www.pzsc.com



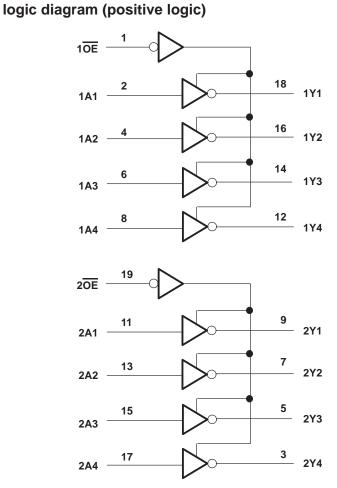


SN54F240, SN74F240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SDFS061A – D2932, MARCH 1987 – REVISED OCTOBER 1993

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC}		
Input voltage range, V _I (see Note 1)		−1.2 V to 7 V
Input current range		– 30 mA to 5 mA
Voltage range applied to any output in th	e disabled or power-off state .	0.5 V to 5.5 V
Voltage range applied to any output in th	e high state	-0.5 V to V _{CC}
Current into any output in the low state:	SN54F240	
	SN74F240	128 mA
Operating free-air temperature range:	SN54F240	–55°C to 125°C
	SN74F240	0°C to 70°C
Storage temperature range		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input voltage ratings may be exceeded provided the input current ratings are observed.



SN54F240, SN74F240 **OCTAL BUFFERS/DRIVERS** WITH 3-STATE OUTPUTS SDFS061A – D2932, MARCH 1987 – REVISED OCTOBER 1993

recommended operating conditions

		SN54F240			S	UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.8			0.8	V
Iк	Input clamp current			-18			-18	mA
IOH	High-level output current			- 12			- 15	mA
IOL	Low-level output current			48			64	mA
TA	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEO	CONDITIONS	S	N54F24)	S	N74F24	0	UNIT
PARAMETER	IES	CONDITIONS	MIN	түр†	MAX	MIN	түр†	MAX	UNIT
VIK	V _{CC} = 4.5 V,	lj = -18 mA			-1.2			-1.2	V
		I _{OH} = – 3 mA	2.4	3.3		2.4	3.3		
VOH	$V_{CC} = 4.5 V$	I _{OH} = - 12 mA	2	3.2					V
VОН		I _{OH} = - 15 mA				2	3.1		v
	V _{CC} = 4.75 V,	I _{OH} = - 3 mA				2.7			
VOL	V _{CC} = 4.5 V	I _{OL} = 48 mA		0.38	0.55				V
VOL	VCC = 4.3 V	I _{OL} = 64 mA					0.42	0.55	v
IOZH	V _{CC} = 5.5 V,	V _O = 2.7 V			50			50	μΑ
IOZL	$V_{CC} = 5.5 V,$	$V_{O} = 0.5 V$			-50			-50	μΑ
lj	$V_{CC} = 5.5 V,$	$V_{I} = 7 V$			0.1			0.1	mA
IIH	$V_{CC} = 5.5 V,$	V _I = 2.7 V			20			20	μΑ
١	V _{CC} = 5.5 V,	V _I = 0.5 V			- 1			- 1	mA
los‡	V _{CC} = 5.5 V,	$V_{O} = 0$	-100		-225	-100		-225	mA
		Outputs high		19	29		19	29	
Icc	$V_{CC} = 5.5 V$	Outputs low		50	75		50	75	mA
		Outputs disabled		42	63		42	63	

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.
[‡] Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.



switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CI RI	CC = 5 V _ = 50 p _ = 500 9 _ = 25°C	F, Ω,	CL RL	= 50 pF = 500 Ω		V,	UNIT
				′F240		SN54F240		SN74F240		
		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
^t PLH	A A	×	2.2	4.7	7	2.2	9	2.2	8	ns
^t PHL	Any A	ř	1.2	3.1	4.7	1.2	6	1.2	5.7	115
^t PZH	ŌĒ	v	1.2	3.1	5.3	1.2	6.7	1.2	6.1	ns
^t PZL	OE	ř	3.2	6.5	9	3.2	10.5	3.2	10	115
^t PHZ	ŌĒ	v	1.2	3.6	5.3	1.2	6.5	1.2	6.3	ns
^t PLZ			1.2	5.6	8	1.2	12.5	1.2	9.5	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. NOTE 2: Load circuits and waveforms are shown in Section 1.



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